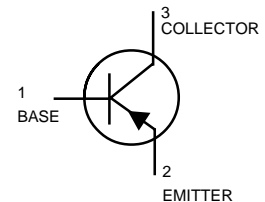
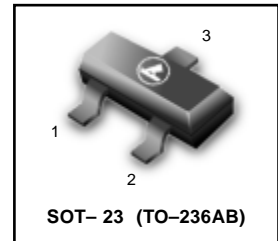


# General Purpose Transistors

## PNP Silicon

- We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

**LMBT3906LT1G**  
**S-LMBT3906LT1G**



### ORDERING INFORMATION

Device	Marking	Shipping
LMBT3906LT1G S-LMBT3906LT1G	2A 2A	3000/Tape & Reel
LMBT3906LT3G S-LMBT3906LT3G	2A 2A	10000/Tape & Reel

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	$V_{CE0}$	- 40	Vdc
Collector–Base Voltage	$V_{CBO}$	- 40	Vdc
Emitter–Base Voltage	$V_{EBO}$	- 5.0	Vdc
Collector Current — Continuous	$I_C$	- 200	mAdc

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR– 5 Board(1) $T_A = 25^\circ\text{C}$	$P_D$	225	mW
Derate above $25^\circ\text{C}$		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	$P_D$	300	mW
Derate above $25^\circ\text{C}$		2.4	mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

### DEVICE MARKING

LMBT3906LT1G = 2A

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage (3) ( $I_C = -1.0 \text{ mAdc}, I_B = 0$ )	$V_{(BR)CEO}$	- 40	—	Vdc
Collector–Base Breakdown Voltage ( $I_C = -10 \mu\text{Adc}, I_E = 0$ )	$V_{(BR)CBO}$	- 40	—	Vdc
Emitter–Base Breakdown Voltage ( $I_E = -10 \mu\text{Adc}, I_C = 0$ )	$V_{(BR)EBO}$	- 5.0	—	Vdc
Base Cutoff Current ( $V_{CE} = -30 \text{ Vdc}, V_{EB} = -3.0 \text{ Vdc}$ )	$I_{BL}$	—	- 50	nAdc
Collector Cutoff Current ( $V_{CE} = -30 \text{ Vdc}, V_{EB} = -3.0 \text{ Vdc}$ )	$I_{CEX}$	—	- 50	nAdc

1. FR–5 =  $1.0 \times 0.75 \times 0.062 \text{ in.}$
2. Alumina =  $0.4 \times 0.3 \times 0.024 \text{ in.}$  99.5% alumina.
3. Pulse Width  $\leq 300 \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

**LMBT3906LT1G ;S-LMBT3906LT1G**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS (2)</b>				
DC Current Gain ( $I_C = -0.1 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )	$h_{FE}$	60	—	—
( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )		80	—	
( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )		100	300	
( $I_C = -50 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )		60	—	
( $I_C = -100 \text{ mAdc}$ , $V_{CE} = -1.0 \text{ Vdc}$ )		30	—	
Collector–Emitter Saturation Voltage ( $I_C = -10 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ )	$V_{CE(sat)}$	—	-0.25	Vdc
( $I_C = -50 \text{ mAdc}$ , $I_B = -5.0 \text{ mAdc}$ )		—	-0.4	
Base–Emitter Saturation Voltage ( $I_C = -10 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ )	$V_{BE(sat)}$	-0.65	-0.85	Vdc
( $I_C = -50 \text{ mAdc}$ , $I_B = -5.0 \text{ mAdc}$ )		—	-0.95	

**SMALL–SIGNAL CHARACTERISTICS**

Current–Gain — Bandwidth Product ( $I_C = -10 \text{ mAdc}$ , $V_{CE} = -20 \text{ Vdc}$ , $f = 100 \text{ MHz}$ )	$f_T$	250	—	MHz
Output Capacitance ( $V_{CB} = -5.0 \text{ Vdc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{obo}$	—	4.5	pF
Input Capacitance ( $V_{EB} = -0.5 \text{ Vdc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )	$C_{ibo}$	—	10	pF
Input Impedance ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{ie}$	2.0	12	k $\Omega$
Voltage Feedback Ratio ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{re}$	0.1	10	$\times 10^{-4}$
Small–Signal Current Gain ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{re}$	100	400	—
Output Admittance ( $V_{CE} = -10 \text{ Vdc}$ , $I_C = -1.0 \text{ mAdc}$ , $f = 1.0 \text{ kHz}$ )	* $h_{oe}$	3.0	60	$\mu\text{mhos}$
Noise Figure ( $V_{CE} = -5.0 \text{ Vdc}$ , $I_C = -100 \mu\text{Adc}$ , $R_s = 1.0 \text{ k}\Omega$ , $f = 1.0 \text{ kHz}$ )	NF	—	4.0	dB

**SWITCHING CHARACTERISTICS**

Delay Time	( $V_{CC} = -3.0 \text{ Vdc}$ , $V_{BE} = 0.5 \text{ Vdc}$ , $I_C = -10 \text{ mAdc}$ , $I_{B1} = -1.0 \text{ mAdc}$ )	$t_d$	—	35	ns
Rise Time		$t_d$	—	35	
Storage Time	( $V_{CC} = -3.0 \text{ Vdc}$ , $I_C = -10 \text{ mAdc}$ , $I_{B1} = I_{B2} = -1.0 \text{ mAdc}$ )	$t_s$	—	225	ns
Fall Time		$t_f$	—	75	

 3. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

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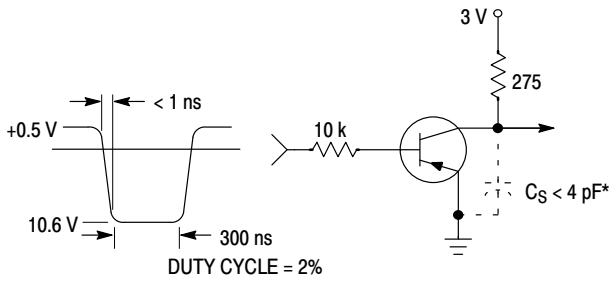


Figure 1. Delay and Rise Time Equivalent Test Circuit

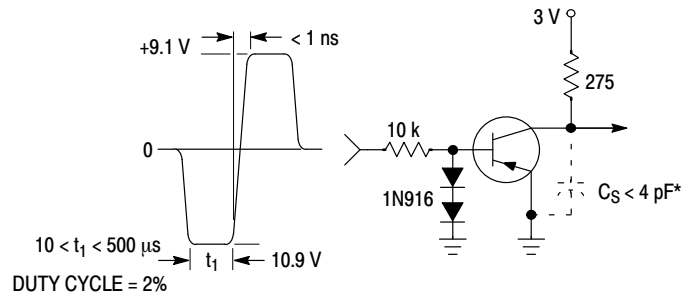


Figure 2. Storage and Fall Time Equivalent Test Circuit

\* Total shunt capacitance of test jig and connectors

TYPICAL TRANSIENT CHARACTERISTICS

—  $T_J = 25^\circ\text{C}$   
 - - -  $T_J = 125^\circ\text{C}$

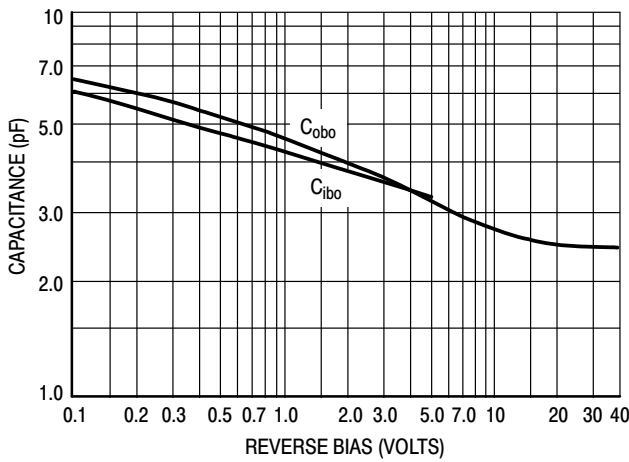


Figure 3. Capacitance

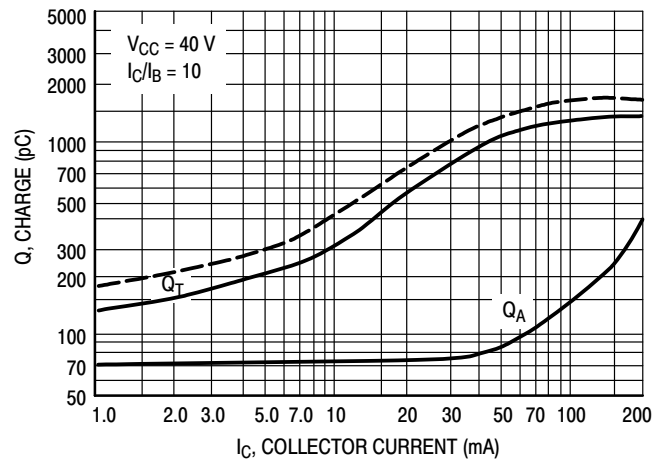


Figure 4. Charge Data

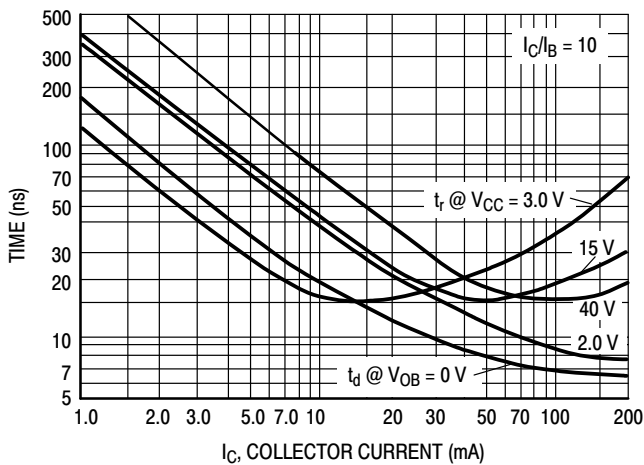


Figure 5. Turn-On Time

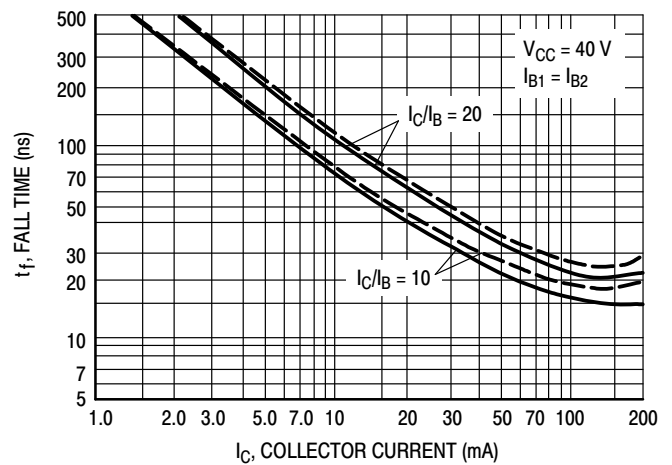


Figure 6. Fall Time

**LMBT3906LT1G ;S-LMBT3906LT1G**

**TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS  
NOISE FIGURE VARIATIONS**

( $V_{CE} = -5.0$  Vdc,  $T_A = 25^\circ\text{C}$ , Bandwidth = 1.0 Hz)

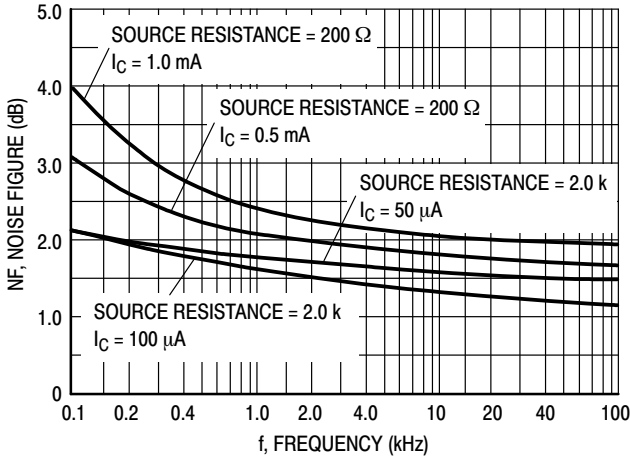


Figure 7.

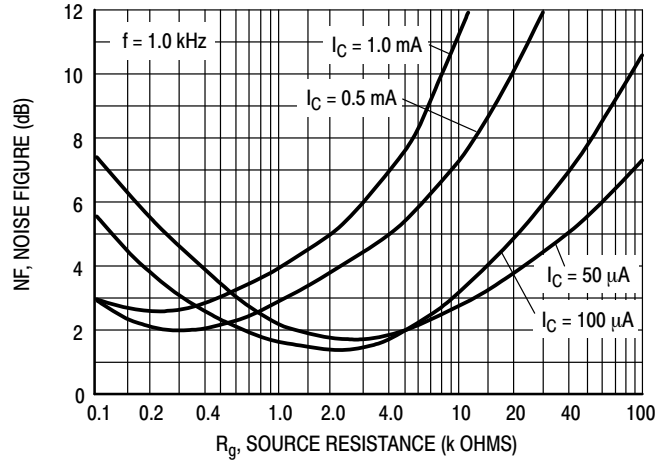


Figure 8.

**h PARAMETERS**

( $V_{CE} = -10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$ )

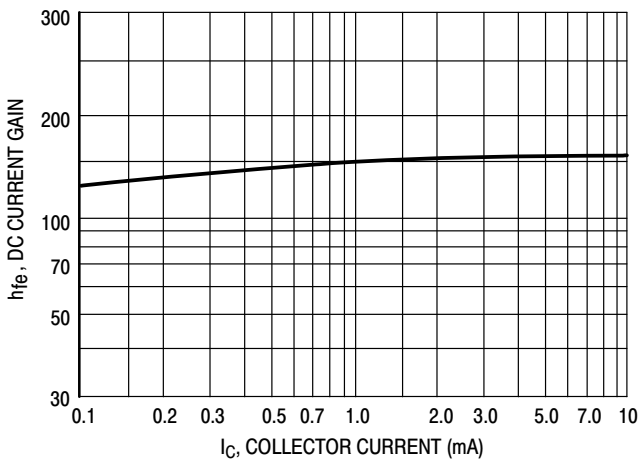


Figure 9. Current Gain

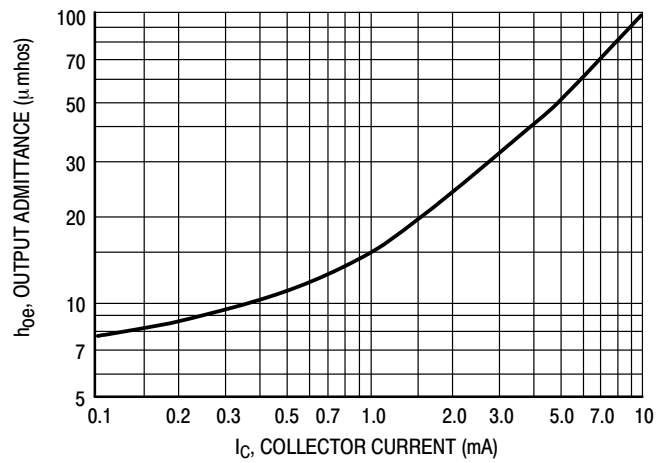


Figure 10. Output Admittance

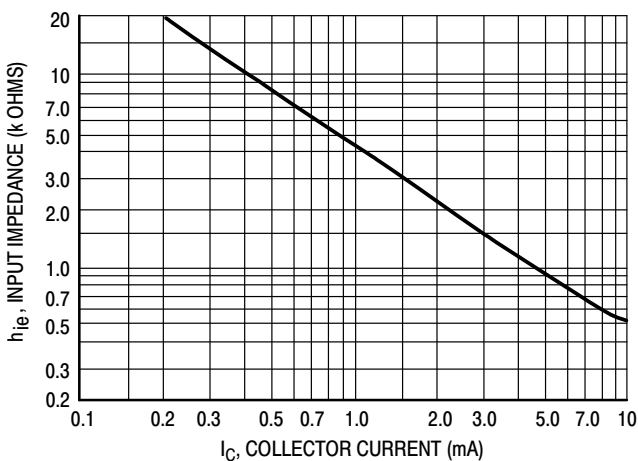


Figure 11. Input Impedance

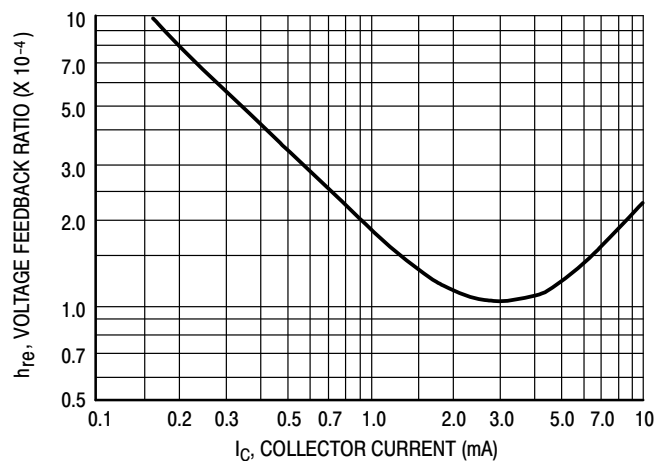


Figure 12. Voltage Feedback Ratio

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TYPICAL STATIC CHARACTERISTICS

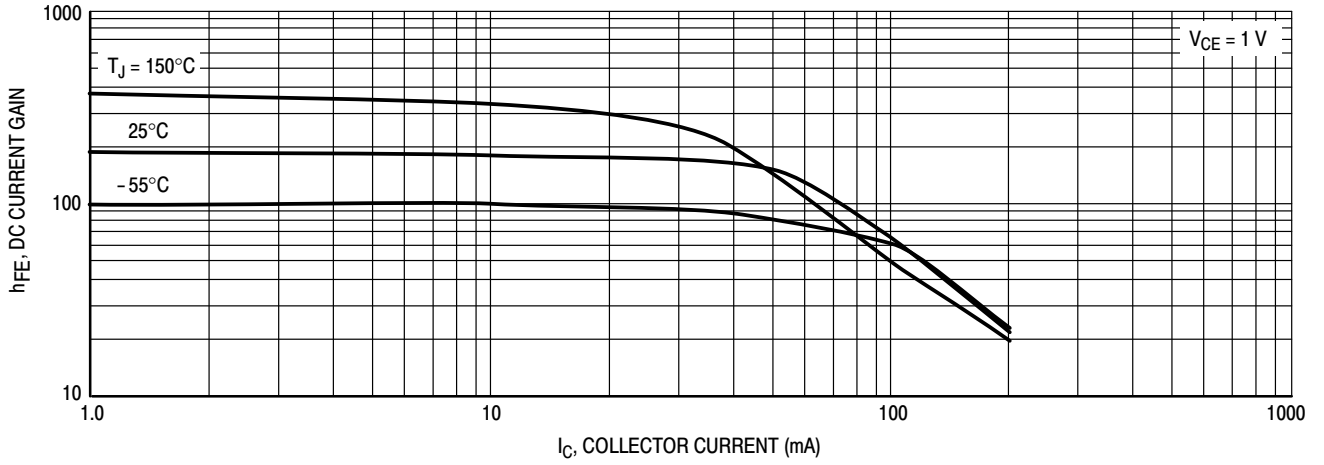


Figure 13. DC Current Gain

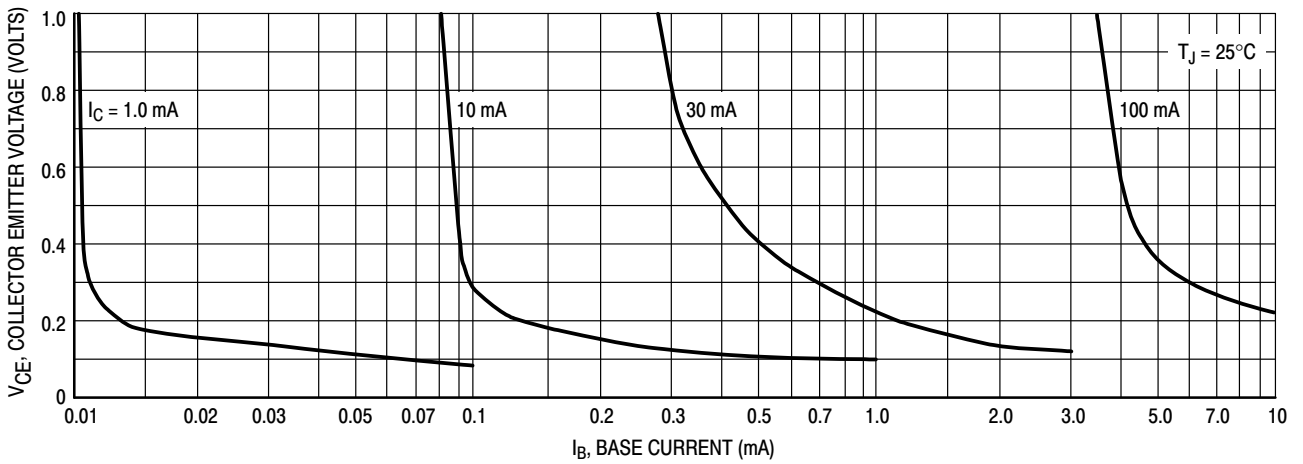


Figure 14. Collector Saturation Region

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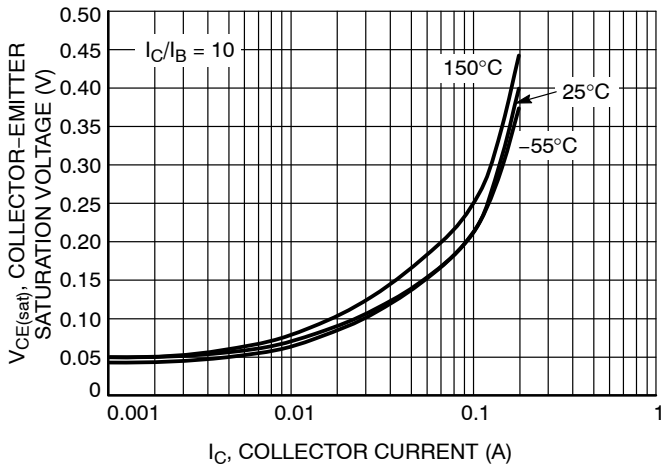


Figure 15. Collector-Emitter Saturation Voltage vs. Collector Current

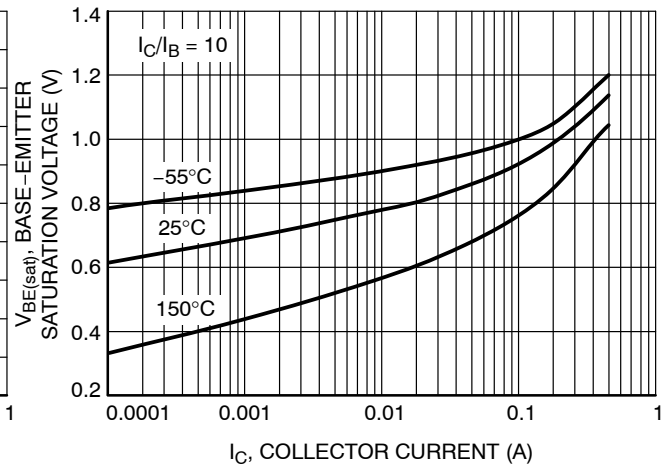


Figure 16. Base-Emitter Saturation Voltage vs. Collector Current

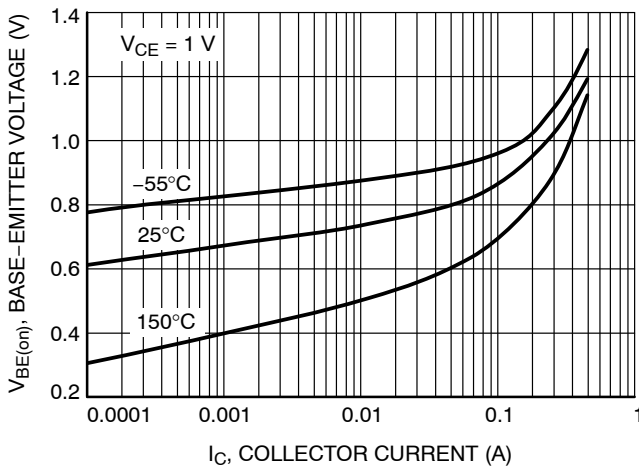


Figure 17. Base-Emitter Voltage vs. Collector Current

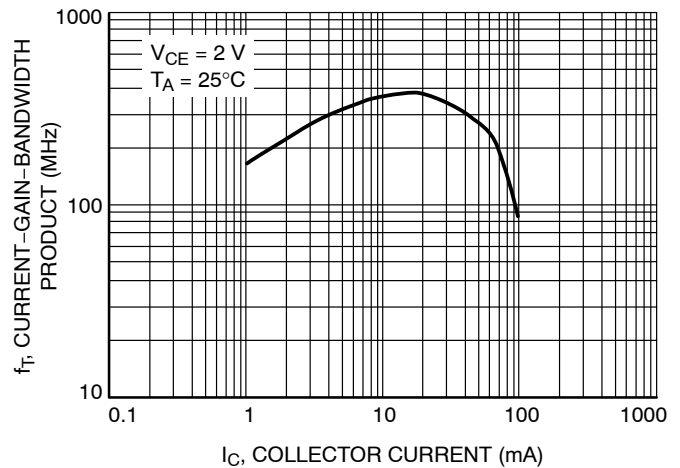


Figure 18. Current Gain Bandwidth vs. Collector Current

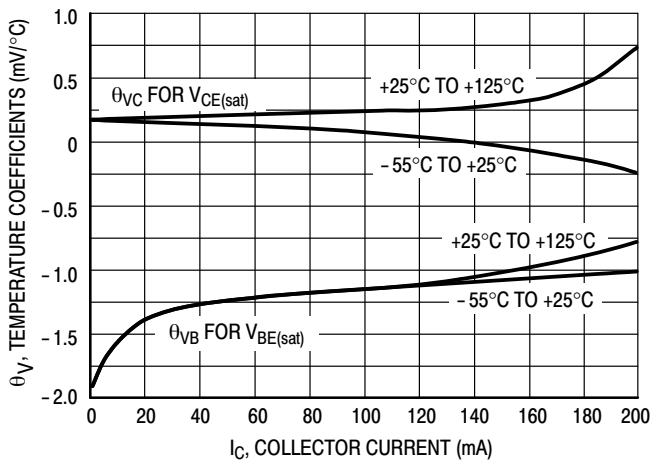


Figure 19. Temperature Coefficients

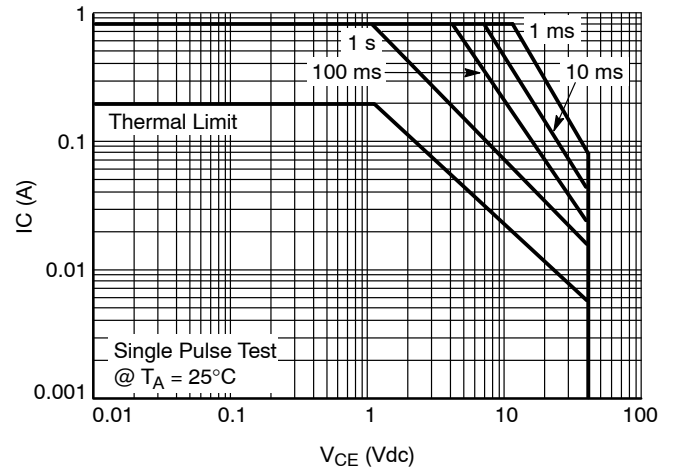
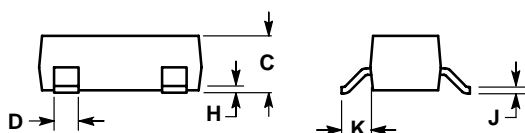
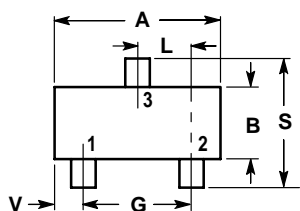


Figure 20. Safe Operating Area

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NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

